NSN 5961-00-104-9949



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-104-9949 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 100.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 1.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** voltage; junction pattern arrangement: pnp **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:**

42498-a43085 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

3 uninsulated wire lead

Terminal Type And Quantity:

Shelf Life:

N/a

Unit Of Measure:

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Demi			

No

Fiig:

A110a0